DATA SHEET



Solid State Relay OCMOS FET

PS7241-2A

8-PIN SOP, 400V BREAK DOWN VOLTAGE 2-ch Optical Coupled MOS FET

DESCRIPTION

The PS7241-2A is a solid state relay containing GaAs LEDs on the light emitting side (input side) and normally open (N.O.) contact MOS FETs on the output side.

It is suitable for analog signal control because of their low offset and high linearity.

* FEATURES

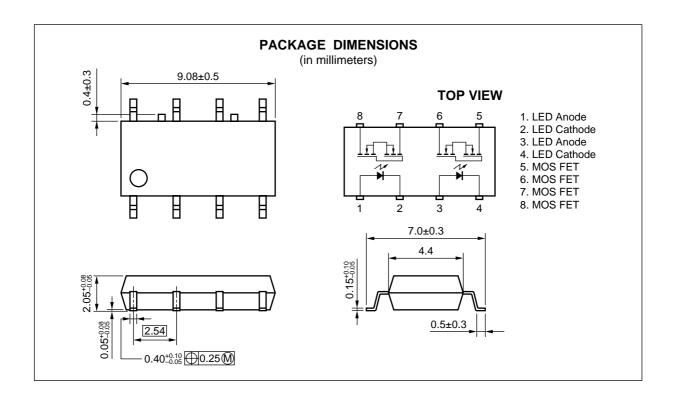
- 2 channel type (1 a + 1 a output)
- Low LED operating current (IF = 2 mA)
- · Designed for AC/DC switching line changer
- Small and thin package (8-pin SOP, Height = 2.1 mm)
- · Low offset voltage
- Ordering number of taping product: PS7241-2A-F3, F4
- UL approved: File No. E72422 (S)
- BSI approved: No. 8241/8242
- CSA approved: No. CA 101391

APPLICATIONS

- · Exchange equipment
- · Measurement equipment
- FA/OA equipment

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



★ ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number*1
PS7241-2A	8-pin SOP	Magazine case 45 pcs	PS7241-2A
PS7241-2A -F3		Embossed Tape 1 500 pcs/reel	
PS7241-2A -F4			

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	50	mA
	Reverse Voltage	VR	5	V
	Power Dissipation	PD	50	mW/ch
	Peak Forward Current*1	IFP	1	Α
MOS FET	Break Down Voltage	VL	400	V
	Continuous Load Current	lι	120	mA
	Pulse Load Current ^{*2} (AC/DC Connection)	ILP	200	mA
	Power Dissipation	Po	180	mW/ch
Isolation Voltage ^{*3}		BV	1 500	Vr.m.s.
Total Power Dissipation		Рт	460	mW
Operating Ambient Temperature		TA	-40 to +80	°C
Storage Temperature		Tstg	-40 to +100	°C

^{*1} PW = 100 μ s, Duty Cycle = 1 %

3

^{*2} PW = 100 ms, 1 shot

^{*3} AC voltage for 1 minute at $T_A = 25$ °C, RH = 60 % between input and output



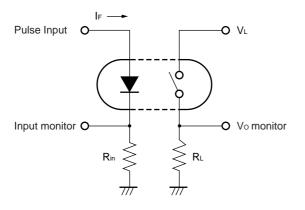
RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

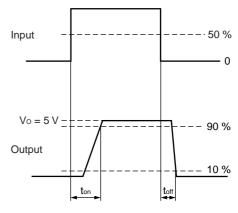
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

★ ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
	Reverse Current	lR	V _R = 5 V			5	μΑ
MOS FET	Off-state Leakage Current	Loff	V _D = 400 V		0.03	1.0	μΑ
	Output Capacitance	Cout	V _D = 0 V, f = 1.0 MHz		65		pF/ch
Coupled	LED On-state Current	IFon	IL = 120 mA			2.0	mA
	On-state Resistance	Ron1	IF = 10 mA, IL = 10 mA		21	30	Ω
		Ron2	I _F = 10 mA, I _L = 120 mA, t ≤ 10 ms		16	25	
	Turn-on Time [™]	ton	IF = 10 mA, Vo = 5 V, PW ≥ 10 ms		0.2	1.0	ms
	Turn-off Time [™]	toff			0.02	0.2	
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVpc	10°			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.4		pF/ch

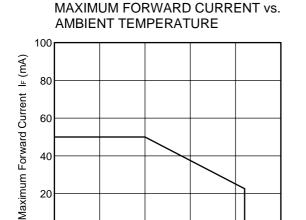
*1 Test Circuit for Switching Time





0 −25

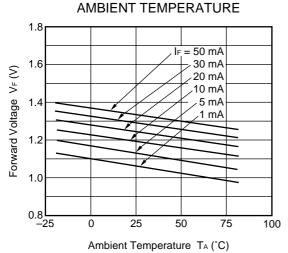
★ TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)



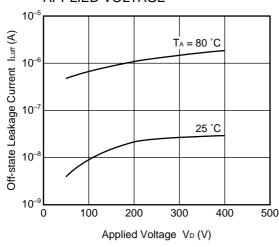
Ambient Temperature TA (°C)

25

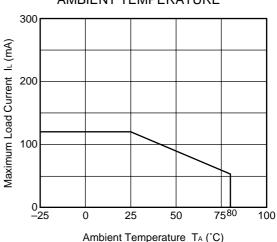
FORWARD VOLTAGE vs.



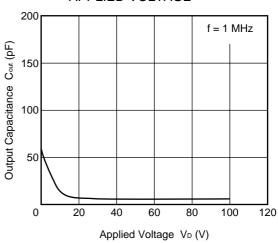
OFF-STATE LEAKAGE CURRENT vs. APPLIED VOLTAGE



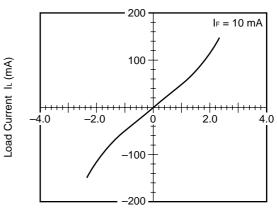
MAXIMUM LOAD CURRENT vs. AMBIENT TEMPERATURE



OUTPUT CAPACITANCE vs. APPLIED VOLTAGE



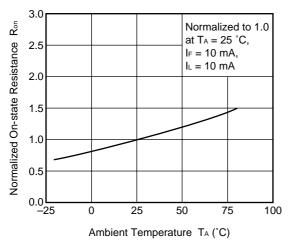
LOAD CURRENT vs. LOAD VOLTAGE



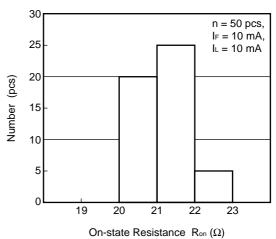
Load Voltage V_L (V)



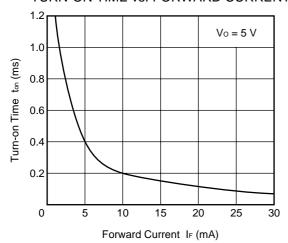
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



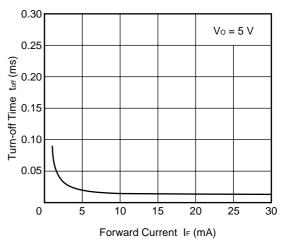
ON-STATE RESISTANCE DISTRIBUTION



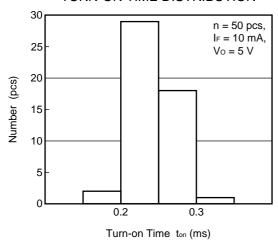
TURN-ON TIME vs. FORWARD CURRENT



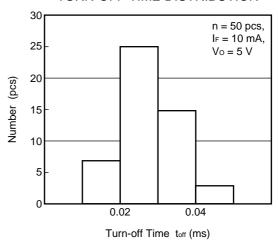
TURN-OFF TIME vs. FORWARD CURRENT



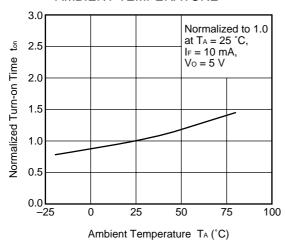
TURN-ON TIME DISTRIBUTION



TURN-OFF TIME DISTRIBUTION

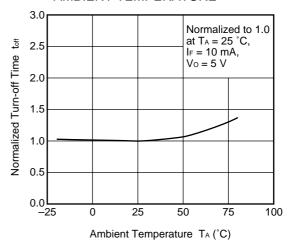


NORMALIZED TURN-ON TIME vs. AMBIENT TEMPERATURE

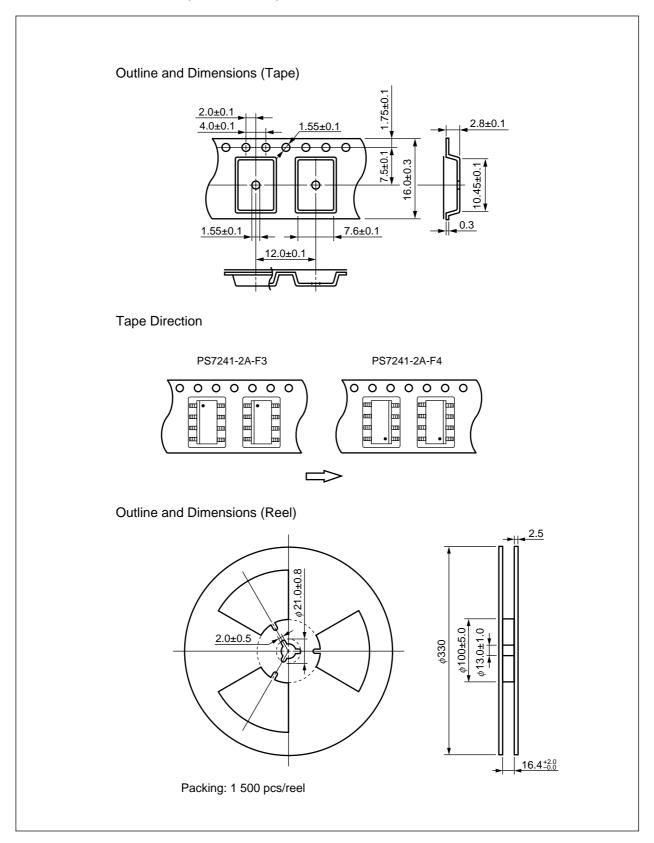


Remark The graphs indicate nominal characteristics.

NORMALIZED TURN-OFF TIME vs. AMBIENT TEMPERATURE



★ TAPING SPECIFICATIONS (in millimeters)





* RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

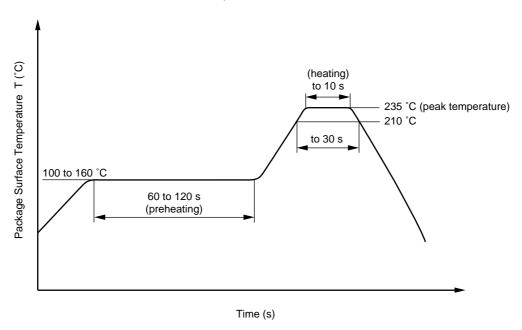
• Peak reflow temperature 235 °C (package surface temperature)

• Time of temperature higher than 210 °C 30 seconds or less

• Number of reflows Two

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Dip soldering

• Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

• Number of times One

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

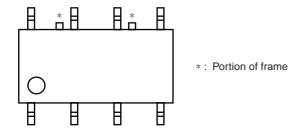
0.2 Wt % is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

· Avoid shorting between portion of frame and leads.



[MEMO]

NEC PS7241-2A

[MEMO]

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

- The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.
- No part of this document may be copied or reproduced in any form or by any means without the prior written
 consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in
 this document.
- NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property
 rights of third parties by or arising from use of a device described herein or any other liability arising from use
 of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other
 intellectual property rights of NEC Corporation or others.
- Descriptions of circuits, software, and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software, and information in the design of the customer's equipment shall be done under the full responsibility of the customer. NEC Corporation assumes no responsibility for any losses incurred by the customer or third parties arising from the use of these circuits, software, and information.
- While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customers must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features.
- NEC devices are classified into the following three quality grades:
 - "Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.
 - Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
 - Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - Specific: Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices is "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact an NEC sales representative in advance.

M7 98.8